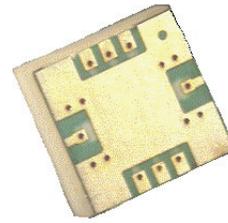


AMMP-6430

27-32 GHz 0.5W Power Amplifier in SMT Package

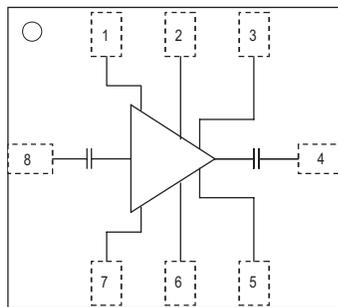
Data Sheet



Description

The AMMP-6430 MMIC is a broadband 1W power amplifier in a surface mount package designed for use in transmitters that operate in various frequency bands between 27GHz and 32GHz. At 30GHz, it provides 29dBm of output power (P-1dB) and 19dB of small-signal gain from a small easy-to-use device. The device has input and output matching circuitry for use in 50Ω environments. The AMMP-6430 also integrates a temperature compensated RF power detection circuit that enables power detection of 0.3V/W. DC bias is simple and the device operates on widely available 5V for current supply (negative voltage only needed for Vg). It is fabricated in a PHEMT process for exceptional power and gain performance.

Pin Connections (Top View)



Pin	Function
1	Vgg
2	Vdd
3	DET_O
4	RF_out
5	DET_R
6	Vdd
7	Vgg
8	RF_in

PACKAGE
BASE
GND

RoHS-Exemption



Please refer to Hazardous substances table on page 11.

Features

- Wide Frequency Range 27-32GHz
- Half watt output power
- 50 Ω match on input and output
- ESD protection (50V MM, and 150V HBM)
- Specifications (Vd=5V, Idsq=650mA)
- Frequency range 27 to 32 GHz
- Small signal Gain of 20dB
- Output power @P-1 of 27dBm (Typ.)
- Input/Output return-loss of -10dB

Applications

- Microwave Radio systems
- Satellite VSAT, DBS Up/Down Link
- LMDS & Pt-Pt mmW Long Haul
- Broadband Wireless Access (including 802.16 and 802.20 WiMax)
- WLL and MMDS loops
- Commercial grade military

Note:

1. This MMIC uses depletion mode pHEMT devices. Negative supply is used for DC gate biasing.



Attention:

Observe Precautions for handling electrostatic sensitive devices.

ESD Machine Model (Class A): 50V
ESD Human Body Model (Class 0): 150V
Refer to Avago Application Note A004R:
Electrostatic Discharge Damage and Control.

Absolute Maximum Ratings [1]

Symbol	Parameters [1]	Units	Value	Notes
V_d	Positive Supply Voltage	V	6	2
V_g	Gate Supply Voltage	V	-3 to 0.5	
I_{dq}	Drain Current	mA	700	
P_D	Power Dissipation	W	5.5	2, 3
P_{in}	CW Input Power	dBm	23	2
$T_{ch, max}$	Maximum Operating Channel Temp.	°C	+155	4, 5
T_{stg}	Storage Case Temp.	°C	-65 to +155	
T_{max}	Maximum Assembly Temp (20 sec max)	°C	+260	

Notes:

1. Operation in excess of any one of these conditions may result in permanent damage to this device.
2. Combinations of supply voltage, drain current, input power, and output power shall not exceed P_D .
3. When operate at this condition with a base plate temperature of 85 °C, the median time to failure (MTTF) is significantly reduced.
4. These ratings apply to each individual FET
5. Junction operating temperature will directly affect the device MTTF. For maximum life, it is recommended that junction temperatures be maintained at the lowest possible levels.

DC Specifications/ Physical Properties [6]

Symbol	Parameters and Test Conditions	Units	Value
I_{dq}	Drain Supply Current ($V_d=5V$, V_g set for I_d Typical)	mA	650
V_g	Gate Supply Operating Voltage ($I_d(Q) = 650$ (mA))	V	-1.1
$R_{\theta JC}$	Thermal Resistance ^[6] (Channel-to-Base Plate)	°C/W	16.8
T_{ch}	Channel Temperature	°C	139.6

Notes:

6. Assume SnPb soldering to an evaluation RF board at 85 °C base plate temperatures. Worst case is at saturated output power when DC power consumption rises to 5.24W with 0.9W RF power delivered to load. Power dissipation is 4.34W and the temperature rise in the channel is 72.9 °C. In this condition, the base plate temperature must be remained below 82.1 °C to maintain maximum operating channel temperature below 155 °C.

AMMP-6430 RF Specifications [1, 2, 3, 4]
 $T_A = 25^\circ\text{C}$, $V_{dd} = 5.0\text{V}$, $I_{dq} = 650\text{mA}$, $V_g = -1.1\text{V}$, $Z_o = 50\Omega$

Symbol	Parameters and Test Conditions	Units	Minimum	Typical	Maximum
Freq	Operational Frequency	GHz	27		32
Gain	Small-signal Gain ^[3, 4] Freq = 27 GHz	dB	16	20	
P_{-1dB}	Output Power at 1dB ^[3] Gain Compression	dBm	26	27	
OIP3	Output Third Order Intercept Point	dBm		35	
RL_{in}	Input Return Loss	dB		10	
RL_{out}	Output Return Loss	dB		10	
Isolation	Reverse Isolation	dB		43	

Notes:

1. Small/Large -signal data measured in packaged form on a 2.4-mm connector based evaluation board at $T_A = 25^\circ\text{C}$.
2. This final package part performance is verified by a functional test correlated to actual performance at one or more frequencies
3. Specifications are derived from measurements in a 50 Ω test environment. Aspects of the amplifier performance may be improved over a narrower bandwidth by application of additional conjugate, linearity, or power matching.
4. Pre-assembly into package performance verified 100% on-wafer published specifications at Frequencies=27, 30, and 32GHz
5. The Gain and P1dB tested at 27GHz guaranteed with measurement accuracy ± 1.5 dB for gain and ± 1.6 dB for P1dB.

AMMP-6430 Typical Performance

(Data obtained from 2.4-mm connector based test fixture, and this data is including connector loss, and board loss.)
 ($T_A = 25^\circ\text{C}$, $V_{dd}=5\text{V}$, $I_{dq}=650\text{mA}$, $V_g=-1.1\text{V}$, $Z_{in} = Z_{out} = 50\Omega$)

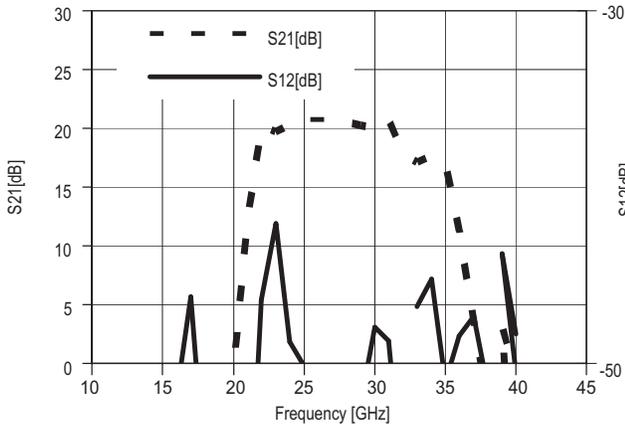


Figure 1. Typical Gain and Reverse Isolation

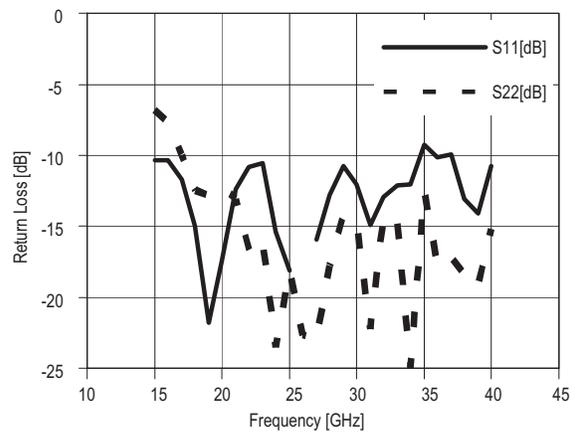


Figure 2. Typical Input & Output Return Loss

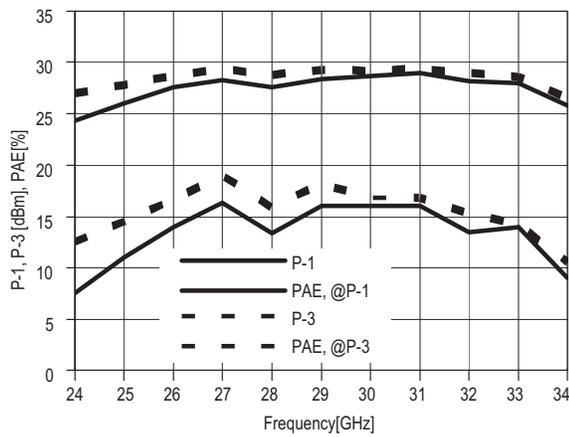


Figure 3. Typical P-1 and PAE

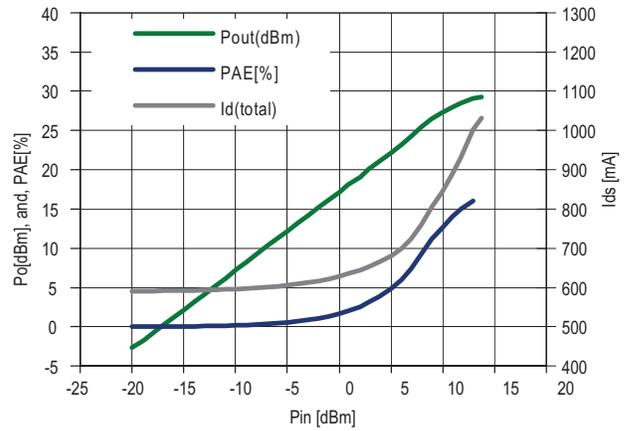


Figure 4. Typical Pout, Ids, and PAE vs. Pin at Freq=30GHz

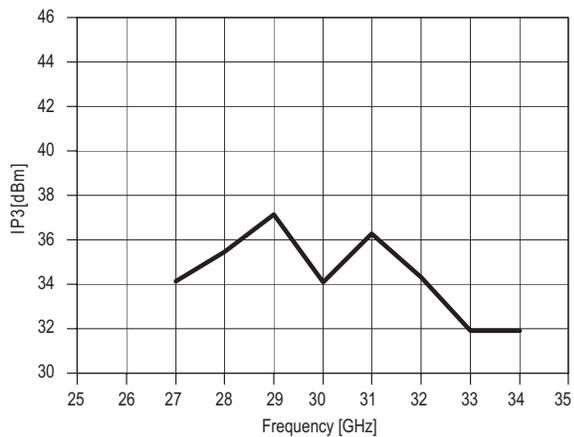


Figure 5. Typical IP3 (Third Order Intercept) @ Pin=-20dBm

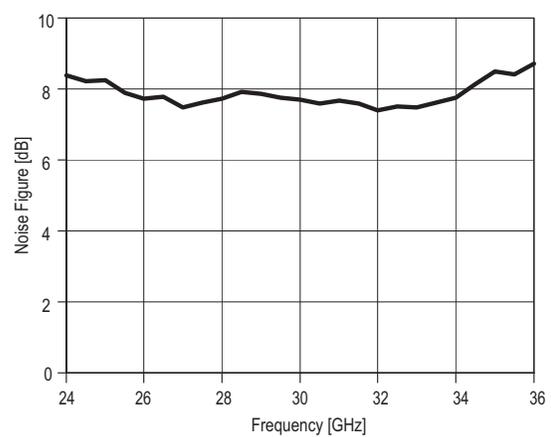


Figure 6. Typical Noise Figure

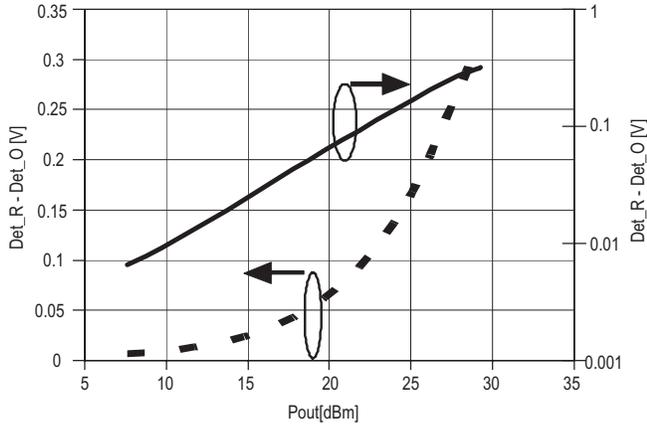


Figure 7. Typical Detector voltage vs. Output Power @30GHz

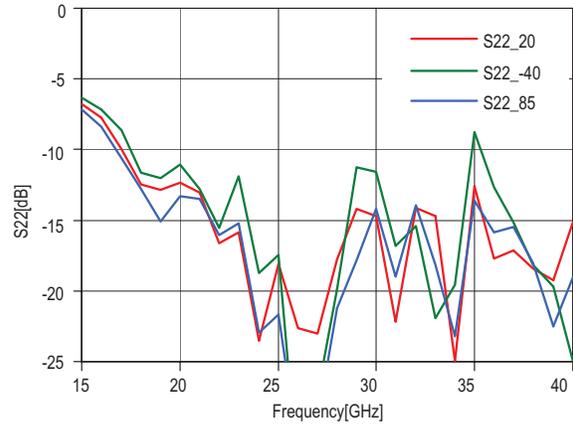


Figure 8. Typical S22 over temperature

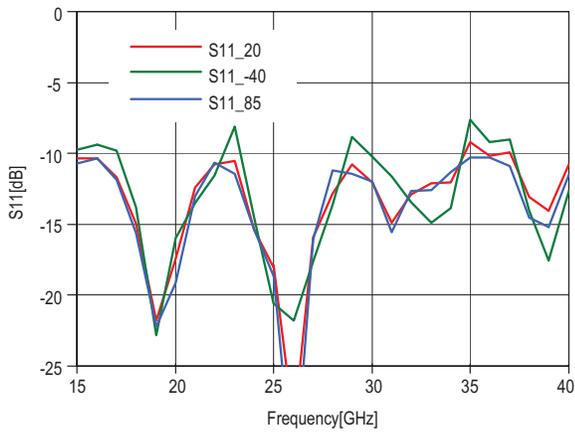


Figure 9. Typical S11 over temperature

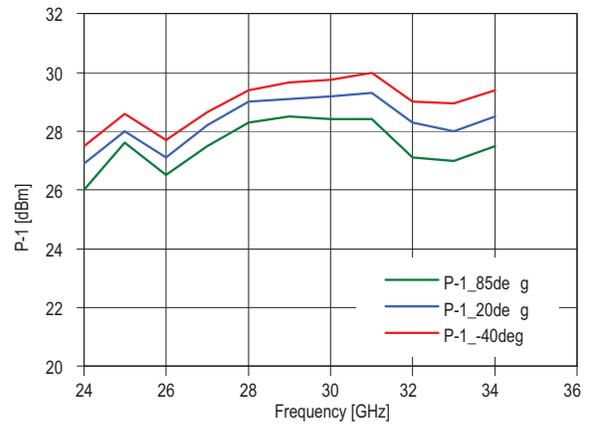


Figure 10. Typical P-1 over temperature

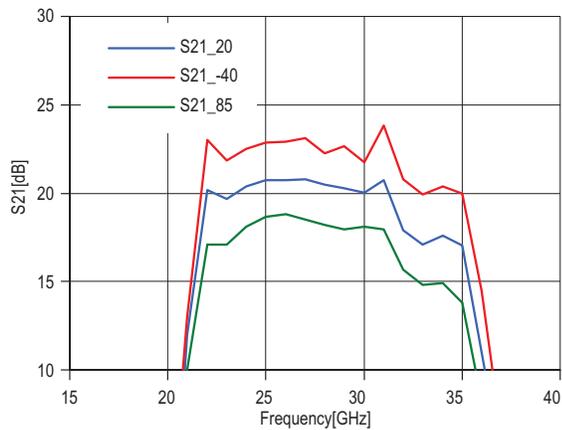


Figure 11. Typical Gain over temperature

Typical Scattering Parameters [1]

($T_A = 25^\circ\text{C}$, $V_{dd} = 5\text{ V}$, $I_{dq} = 650\text{ mA}$, $Z_{in} = Z_{out} = 50\Omega$)

www.DataSheet4U.com

Freq [GHz]	S11			S21			S12			S22		
	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase
1	-0.077	0.991	-30.672	-60.460	0.001	156.200	-81.678	8.24E-05	13.553	-0.075	0.991	-31.001
2	-0.244	0.972	-61.135	-52.134	0.002	7.598	-79.982	1.00E-04	-1.433	-0.218	0.975	-61.826
3	-0.507	0.943	-91.481	-55.059	0.002	-178.810	-78.816	1.15E-04	-26.240	-0.450	0.949	-92.759
4	-0.857	0.906	-121.770	-62.791	0.001	135.030	-73.965	2.00E-04	-79.414	-0.847	0.907	-123.780
5	-1.286	0.862	-152.370	-43.769	0.006	72.309	-66.459	4.75E-04	-89.529	-1.465	0.845	-152.600
6	-1.834	0.810	176.860	-43.125	0.007	-55.096	-61.854	8.08E-04	-141.380	-1.593	0.832	177.570
7	-2.497	0.750	146.160	-47.710	0.004	-138.310	-59.371	1.08E-03	-174.860	-2.056	0.789	145.900
8	-3.218	0.690	115.480	-50.926	0.003	167.090	-58.859	1.14E-03	151.750	-2.614	0.740	114.510
9	-3.952	0.634	84.820	-48.273	0.004	127.030	-51.689	2.60E-03	128.260	-3.234	0.689	82.673
10	-4.734	0.580	54.869	-47.156	0.004	82.462	-49.760	3.25E-03	76.311	-3.919	0.637	51.597
11	-5.372	0.539	26.213	-46.361	0.005	37.278	-47.391	4.27E-03	33.764	-4.545	0.593	21.330
12	-5.892	0.507	-1.577	-49.213	0.003	16.009	-48.433	3.79E-03	-0.070	-5.413	0.536	-7.654
13	-6.334	0.482	-28.136	-43.321	0.007	-18.990	-47.536	4.20E-03	-31.732	-4.738	0.580	-29.552
14	-6.785	0.458	-52.977	-49.276	0.003	-50.499	-50.113	3.12E-03	-62.027	-4.740	0.579	-63.489
15	-7.246	0.434	-75.942	-48.968	0.004	-66.480	-47.510	4.21E-03	-80.734	-5.196	0.550	-93.519
16	-7.822	0.406	-95.873	-50.759	0.003	79.915	-49.051	3.53E-03	-117.620	-5.850	0.510	-122.580
17	-8.056	0.396	-113.940	-31.831	0.026	37.293	-53.232	2.18E-03	-135.710	-6.891	0.452	-151.530
18	-8.011	0.398	-130.700	-19.650	0.104	-11.371	-54.404	1.90E-03	-136.240	-8.605	0.371	179.660
19	-8.003	0.398	-150.530	-8.565	0.373	-65.975	-52.389	2.40E-03	-100.790	-11.491	0.266	151.610
20	-8.086	0.394	-172.380	2.944	1.404	-130.730	-45.317	5.42E-03	-135.360	-15.971	0.159	128.630
21	-10.147	0.311	160.910	16.205	6.460	130.360	-44.518	5.94E-03	179.470	-32.906	0.023	80.680
22	-10.495	0.299	156.560	19.584	9.533	-6.027	-44.477	5.97E-03	146.120	-18.247	0.122	-170.070
23	-12.051	0.250	132.580	19.712	9.674	-99.417	-44.466	5.98E-03	129.370	-18.242	0.122	169.400
24	-15.378	0.170	122.010	20.404	10.476	174.220	-44.254	6.13E-03	102.170	-17.689	0.130	159.240
25	-16.652	0.147	127.100	20.339	10.398	91.597	-44.452	5.99E-03	63.925	-18.009	0.126	147.290
26	-17.111	0.139	113.670	19.880	9.862	16.978	-44.351	6.06E-03	36.998	-19.138	0.110	134.330
27	-23.026	0.071	100.620	20.040	10.046	-54.022	-45.333	5.41E-03	1.733	-23.261	0.069	137.140
28	-20.256	0.097	166.160	20.218	10.255	-128.560	-52.770	2.30E-03	-49.664	-18.834	0.114	161.640
29	-14.571	0.187	152.630	20.087	10.100	157.600	-49.161	3.48E-03	-75.571	-15.869	0.161	147.670
30	-13.363	0.215	128.640	19.761	9.729	85.669	-57.520	1.33E-03	15.834	-15.535	0.167	128.380
31	-11.814	0.257	107.980	19.830	9.807	10.808	-86.823	4.56E-05	-92.886	-14.211	0.195	109.870
32	-10.715	0.291	83.770	19.352	9.282	-68.718	-58.807	1.15E-03	-82.154	-13.484	0.212	82.184
33	-10.889	0.285	65.105	18.619	8.531	-150.100	-62.898	7.16E-04	92.036	-14.452	0.189	72.563
34	-11.417	0.269	41.069	18.093	8.028	124.500	-51.835	2.56E-03	-4.332	-15.301	0.172	53.869
35	-12.098	0.248	36.792	15.162	5.730	14.850	-52.719	2.31E-03	-115.640	-12.933	0.226	56.976
36	-11.897	0.254	24.365	7.101	2.265	-75.509	-58.568	1.18E-03	-48.164	-12.205	0.245	32.346
37	-11.125	0.278	13.967	-0.825	0.909	-142.060	-57.430	1.34E-03	-124.980	-12.066	0.249	15.583
38	-10.020	0.316	-0.758	-7.753	0.410	161.700	-52.497	2.37E-03	-154.340	-11.605	0.263	0.967
39	-9.222	0.346	-16.019	-13.812	0.204	110.760	-56.625	1.47E-03	116.090	-11.065	0.280	-12.574
40	-8.609	0.371	-32.089	-19.209	0.110	62.155	-55.294	1.72E-03	91.256	-10.402	0.302	-26.857
41	-8.175	0.390	-47.230	-24.340	0.061	13.948	-56.805	1.44E-03	1.705	-9.889	0.320	-40.144
42	-7.588	0.417	-62.593	-29.416	0.034	-31.372	-57.472	1.34E-03	-87.233	-9.293	0.343	-52.531
43	-7.587	0.417	-78.246	-34.254	0.019	-72.562	-64.193	6.17E-04	-136.190	-8.532	0.374	-64.211
44	-7.506	0.421	-89.361	-38.657	0.012	-112.560	-69.135	3.49E-04	-109.180	-7.654	0.414	-77.188
45	-7.332	0.430	-101.290	-43.475	0.007	-145.910	-60.759	9.16E-04	-29.843	-7.062	0.444	-90.938

Note:

1. Data obtained from a 2.4-mm connector based module, and this data is including connector loss, and board loss.

AMMP-6430 Application and Usage

Recommended quiescent DC bias condition for optimum power and linearity performances is $V_d=5$ volts with V_g (-1.1V) set for $I_d=650$ mA. Minor improvements in performance are possible depending on the application. The drain bias voltage range is 3 to 5V. A single DC gate supply connected to V_g will bias all gain stages. Muting can be accomplished by setting V_g to the pinch-off voltage V_p .

A simplified schematic for the AMMP6430 MMIC die is shown in Figure 12. The MMIC die contains ESD and over voltage protection diodes for V_g , and V_d terminals. The package diagram for the recommended assembly is shown in Figure 13. In finalized package form, ESD diodes protect all possible ESD or over voltage damages between V_{gg} and ground, V_{gg} and V_{dd} , V_{dd} and ground. Typical ESD diode current versus diode voltage for 11-connected diodes in series is shown in Figure 14. Under the recommended DC quiescent biasing condition at $V_{ds}=5$ V, $I_{ds}=650$ mA, $V_{gg}=-1$ V, typical gate terminal current is approximately 0.3mA. If an active biasing technique is selected for the AMMP6430 MMIC PA DC biasing, the active biasing circuit must have more than 10-times higher internal current that the gate terminal current.

An optional output power detector network is also provided. The differential voltage between the Det-Ref and Det-Out pads can be correlated with the RF power

emerging from the RF output port. The detected voltage is given by :

$$V = (V_{ref} - V_{det}) - V_{ofs}$$

where V_{ref} is the voltage at the DET_R port, V_{det} is a voltage at the DET_0 port, V_{ofs} and is the zero-input-power offset voltage.

There are three methods to calculate V_{ofs} :

1. V_{ofs} can be measured before each detector measurement (by removing or switching off the power source and measuring $V_{ref} - V_{det}$). This method gives an error due to temperature drift of less than 0.01dB/50°C.
2. V_{ofs} can be measured at a single reference temperature. The drift error will be less than 0.25dB.
3. V_{ofs} can either be characterized over temperature and stored in a lookup table, or it can be measured at two temperatures and a linear fit used to calculate V_{ofs} at any temperature. This method gives an error close to the method #1.

The RF ports are AC coupled at the RF input to the first stage and the RF output of the final stage. No ground wires are needed since ground connections are made with plated through-holes to the backside of the device.

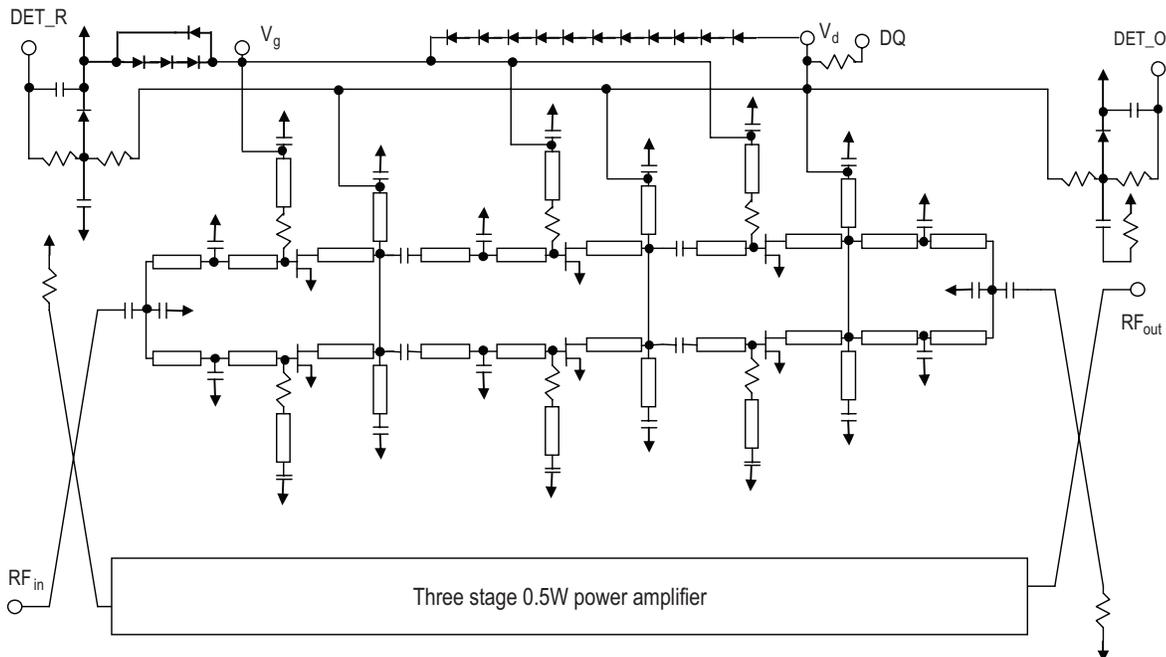
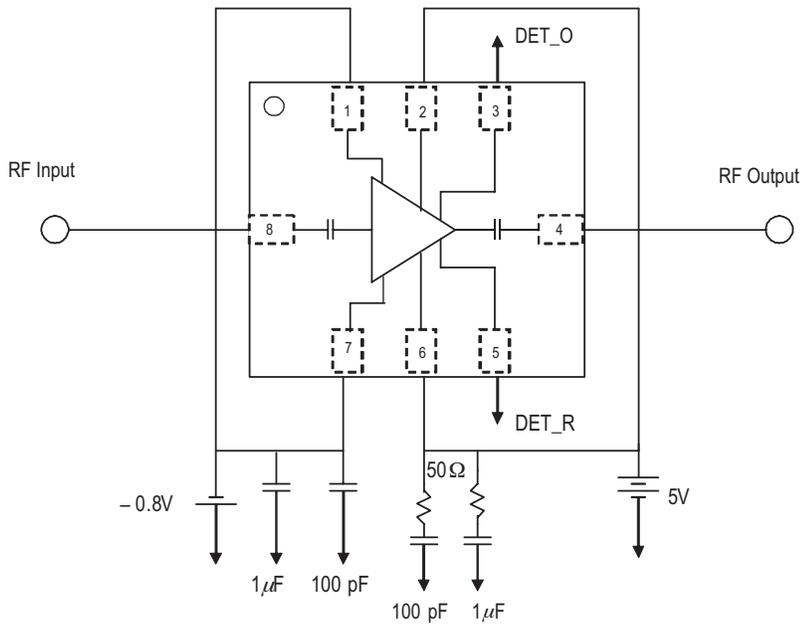


Figure 12. Simplified schematic for the MMIC die



Pin	Function
1	Vgg
2	Vdd
3	DET_O
4	RF_out
5	DET_R
6	Vdd
7	Vgg
8	RF_in

Figure 13. Typical DC connection

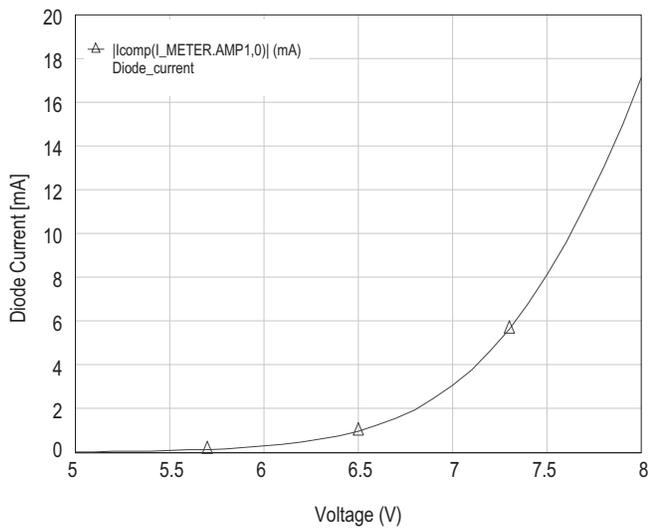


Figure 14. Typical ESD diode current versus diode voltage for 11-connected diodes in series

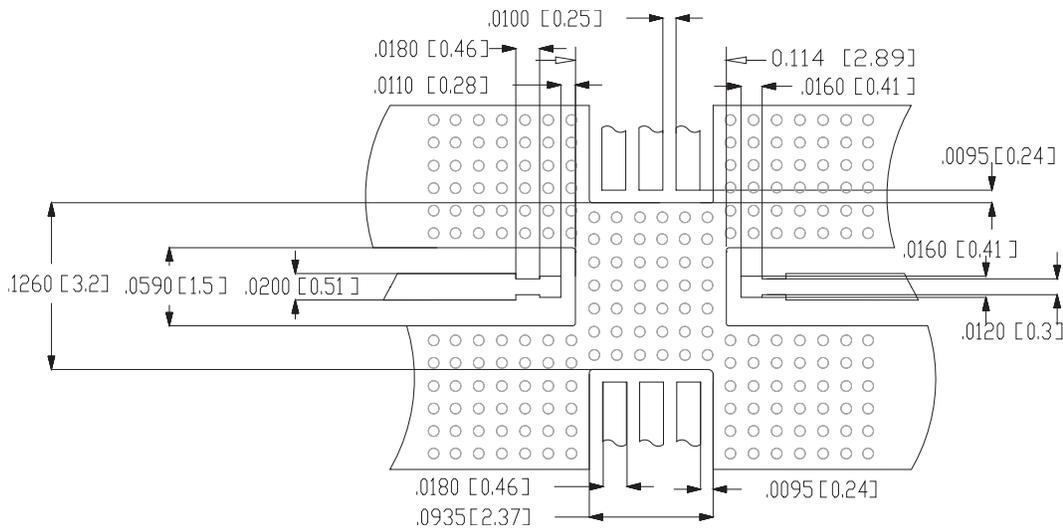


Figure 15a. Suggested PCB Land Pattern and Stencil Layout

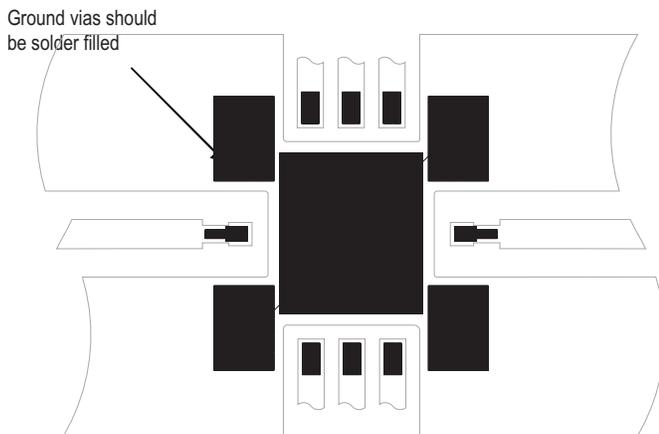


Figure 15b. PCB Land Pattern and Stencil Layouts

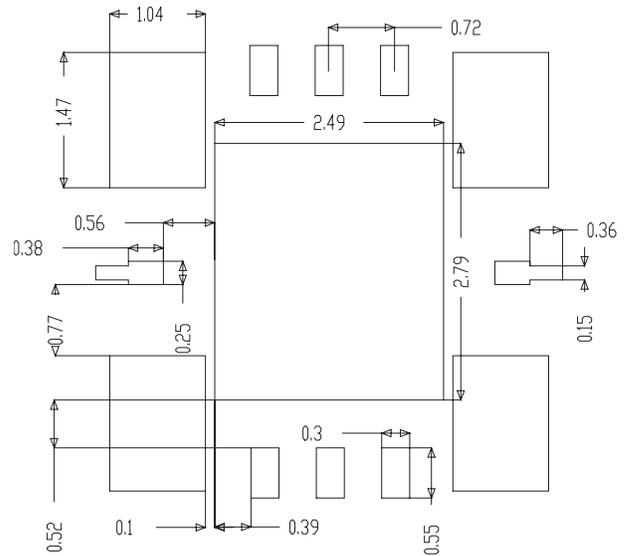


Figure 15c. Stencil Outline Drawing (mm)

The AMMP Packaged Devices are compatible with high volume surface mount PCB assembly processes.

The PCB material and mounting pattern, as defined in the data sheet, optimizes RF performance and is strongly recommended. An electronic drawing of the land pattern is available upon request from Avago Sales & Application Engineering.

Manual Assembly

- Follow ESD precautions while handling packages.
- Handling should be along the edges with tweezers.
- Recommended attachment is conductive solder paste. Please see recommended solder reflow profile. Neither Conductive epoxy or hand soldering is recommended.
- Apply solder paste using a stencil printer or dot placement. The volume of solder paste will be dependent on PCB and component layout and should be controlled to ensure consistent mechanical and electrical performance.
- Follow solder paste and vendor's recommendations when developing a solder reflow profile. A standard profile will have a steady ramp up from room temperature to the pre-heat temp. to avoid damage due to thermal shock.
- Packages have been qualified to withstand a peak temperature of 260°C for 20 seconds. Verify that the profile will not expose device beyond these limits.

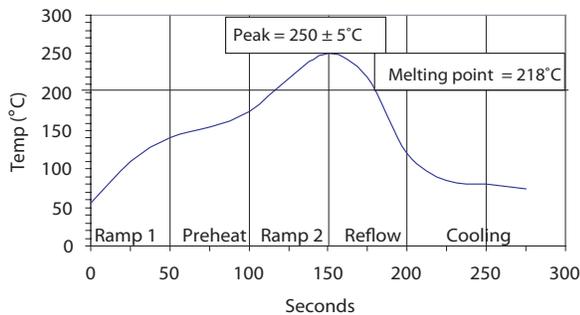


Figure 16. Suggested Lead-Free Reflow Profile for SnAgCu Solder Paste

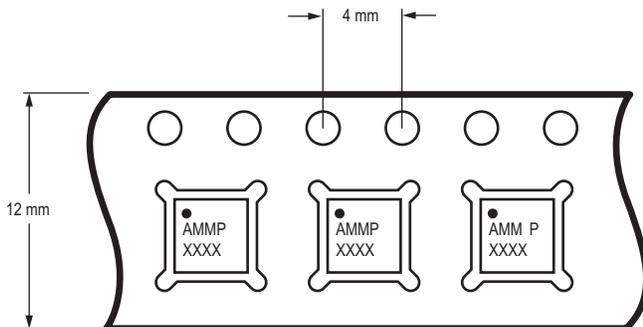
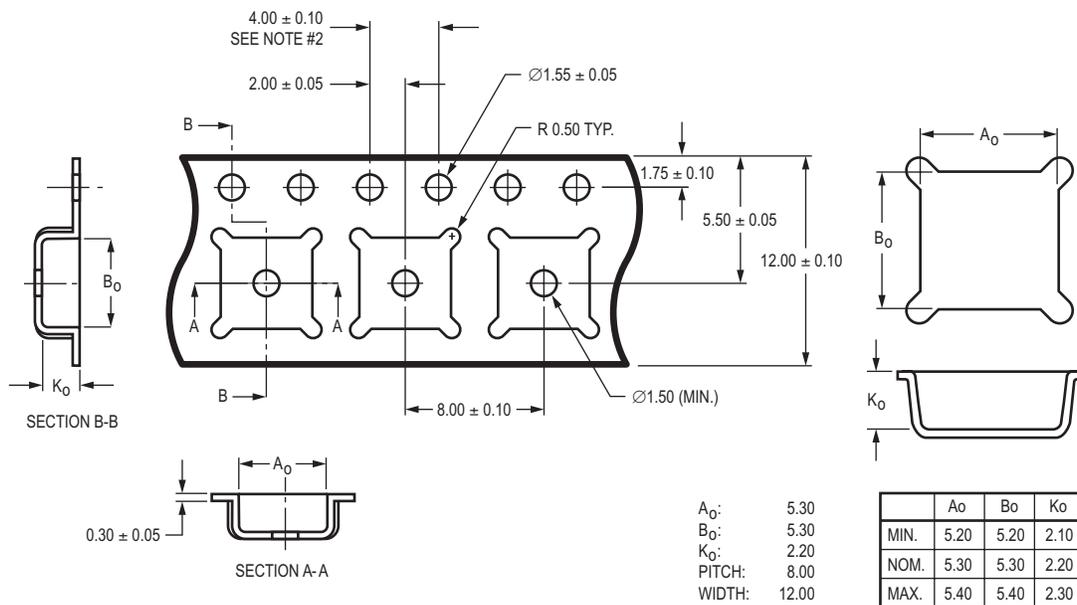
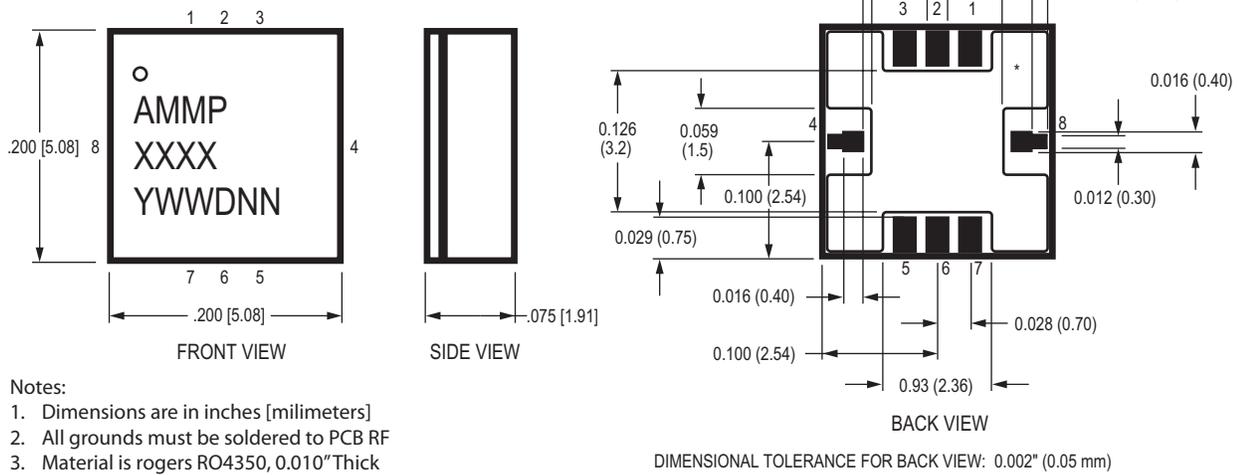
A properly designed solder screen or stencil is required to ensure optimum amount of solder paste is deposited onto the PCB pads. The recommended stencil layout is shown in Figure 15b. The stencil has a solder paste deposition opening approximately 70% to 90% of the PCB pad. Reducing stencil opening can potentially generate more voids underneath. On the other hand, stencil openings larger than 100% will lead to excessive solder paste smear or bridging across the I/O pads. Considering the fact that solder paste thickness will directly affect the quality of the solder joint, a good choice is to use a laser cut stencil composed of 0.127mm (5 mils) thick stainless steel which is capable of producing the required fine stencil outline.

The most commonly used solder reflow method is accomplished in a belt furnace using convection heat transfer. The suggested reflow profile for automated reflow processes is shown in Figure 16. This profile is designed to ensure reliable finished joints. However, the profile indicated in Figure 1 will vary among different solder pastes from different manufacturers and is shown here for reference only.

AMMP-6430 Part Number Ordering Information

Part Number	Devices Per Container	Container
AMMP-6430-BLKG	10	Antistatic bag
AMMP-6430-TR1G	100	7" Reel
AMMP-6430-TR2G	500	7" Reel

Package, Tape & Reel, and Ordering Information



- Notes:**
- A₀ and B₀ measured at 0.3 Mm above base of pocket.
 - 10 Pitches cumulative tolerance is ± 0.2 Mm.
 - Dimensions are in millimeters (mm).



Names and Contents of the Toxic and Hazardous Substances or Elements in the Products
 产品中有毒有害物质或元素的名称及含量

Part Name 部件名称	Toxic and Hazardous Substances or Elements 有毒有害物质或元素					
	Lead (Pb) 铅 (Pb)	Mercury (Hg) 汞 (Hg)	Cadmium (Cd) 镉 (Cd)	Hexavalent (Cr(VI)) 六价 铬 (Cr(VI))	Polybrominated biphenyl (PBB) 多 溴联苯 (PBB)	Polybrominated diphenylether (PBDE) 多溴二苯醚 (PBDE)
100pF capacitor	x	o	o	o	o	o
<p>o: indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006. x: indicates that the content of the toxic and hazardous substance in at least one homogeneous material of the part exceeds the concentration limit requirement as described in SJ/T 11363-2006. (The enterprise may further explain the technical reasons for the "x" indicated portion in the table in accordance with the actual situations.)</p> <p>o: 表示该有毒有害物质在该部件所有均质材料中的含量均在 SJ/T 11363-2006 标准规定的限量要求以下。 x: 表示该有毒有害物质至少在该部件的某一均质材料中的含量超出 SJ/T 11363-2006 标准规定的限量要求。 (企业可在此处, 根据实际情况对上表中打"x"的技术原因进行进一步说明。)</p>						

Note: EU RoHS compliant under exemption clause of "lead in electronic ceramic parts (e.g. piezoelectronic devices)"

For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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